GMGarboMicro Semiconductor

DB201S thru DB207S

SURFACE MOUNT GLASS PASSIVATED BRIDEG RECTIFIERS

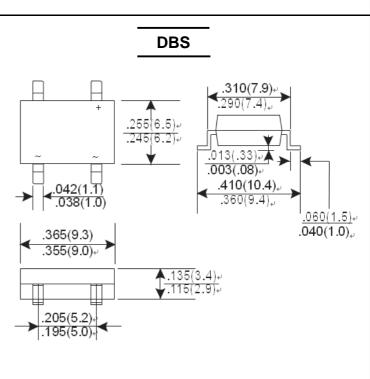
REVERSE VOLTAGE - 50 to 1000Volts FORWARD CURRENT - 2.0 Amperes

FEATURES

- Rating to 1000V PRV
- Ideal for printed circuit board
- Low forward voltage drop, high current capability
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- ●Lead tin Pb/Sn copper
- The plastic material has UL flammability classification 94V-0

MECHANICAL DATA

- Polarit: As marked on Body
- ●Weight: 0.02 ounces,0.38 gras
- Mounting position: Any



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 $^\circ\!\!\!{\rm C}$ ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

| CHARACTERISTICS | SYMBOL | DB201S | DB202S | DB203S | DB204S | DB205S | DB206S | DB207S | UNIT |
|---|------------------|-------------|--------|--------|--------|--------|--------|--------|------------------|
| Maximum Recurrent Peak Reverse Voltage | Vrrm | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS Voltage | Vrms | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC Blocking Voltage | VDC | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum Average Forward Rectified Current @TA=40°C | I(AV) | 2.0 | | | | | | А | |
| Peak Forward Surage Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC .Method) | IFSM | 60 | | | | | | | A |
| Maximum Forward Voltage at 2.0A DC | VF | 1.1 | | | | | | | V |
| Maximum DC Reverse Current @TJ=25°C at Rated DC Blocking Voltage @TJ=125°C | lr | 10 500 | | | | | | | uA |
| I ² t Rating for Fusing (t<8.3ms) | l ² t | 10.4 | | | | | | | A ² s |
| Typical Junction capacitance Per Element(Note1) | CJ | 25 | | | | | | | pF |
| Typical Thermal Resistance (Note2) | Rejc | 40 | | | | | | | °C/W |
| Operating Temperature Range | TJ | -55 to +150 | | | | | | | °C |
| Storage Temperature Range | Tstg | -55 to +150 | | | | | | | °C |

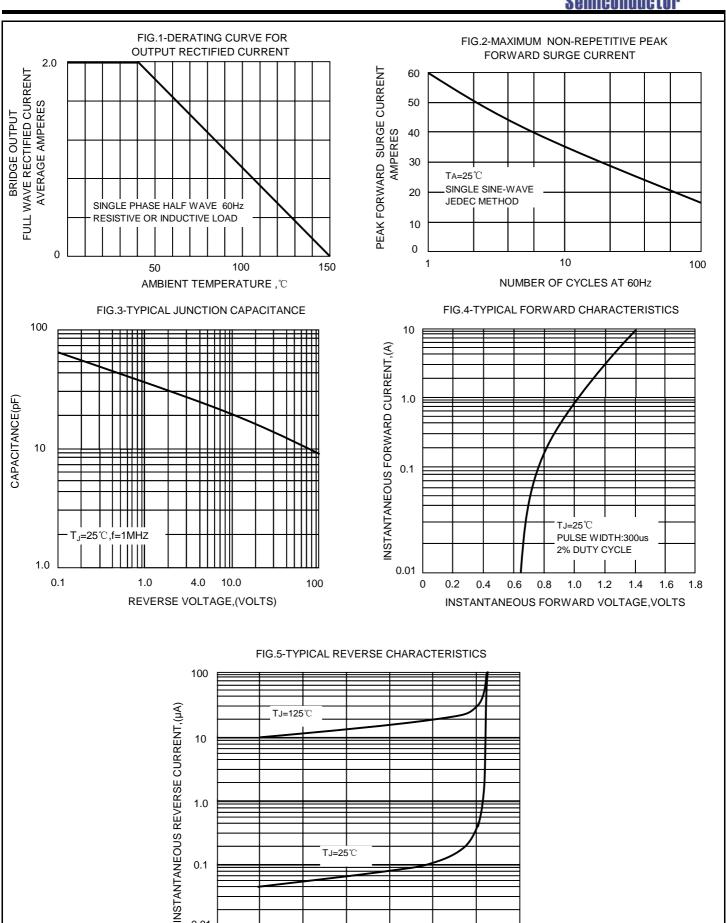
Note:1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC

2. Thermal resistance from junction to ambient mounted on P.C.B

with 0.5*0.5"(13*13mm) copper pads.

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RATING AND CHARACTERISTIC CURVES DB201S thru DB207S



80 PERCENT OF RATED PEAK REVERSE VOLTAGE,(%)

60

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100

140

120

0.01 0

20

40

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